NSN 5961-01-089-2022

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-089-2022 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Overall Diameter:** 0.830 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 550.0 collector to emitter voltage/static/base open and 750.0 collector to emitter reverse voltage and 750.0 collector to base voltage, dc and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 4.00 amperes source cutoff current and 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 80.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No